TT2194



Switching Regulator Applications

Preliminary

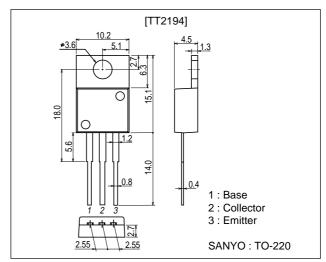
Features

- · High breakdown voltage and high reliability.
- · Fast switching speed.
- · Wide ASO.

www.DataSheet4U.coAdoption of MBIT process.

Package Dimensions

unit : mm 2010C



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		500	V
Collector-to-Emitter Voltage	VCEO		400	V
Emitter-to-Base Voltage	VEBO		7	V
Collector Current	IC		12	Α
Collector Current (Pulse)	ICP	PW≤300μs, duty cycle≤10%	20	Α
Base Current	ΙΒ		3.5	Α
Callagter Dissination	PC		1.75	W
Collector Dissipation		Tc=25°C	50	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Parameter Symbol Conditions		Unit			
r didilietei		Conditions	min	typ	max	l Ollit
Collector Cutoff Current	ІСВО	VCB=400V, IE=0			10	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =5V, I _C =0			10	μΑ

Continued on next page.

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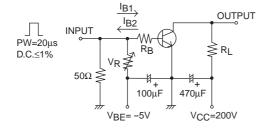
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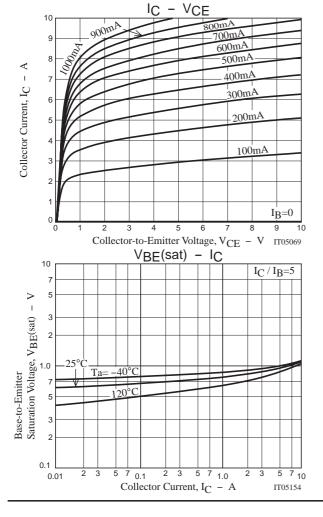
Parameter	Symbol Conditions	Conditions	Ratings			Unit
		min	typ	max	Offic	
	hFE1	V _{CE} =5V, I _C =1.2A	20*		50*	
DC Current Gain	hFE2	V _{CE} =5V, I _C =6A	10			
	hFE3	V _{CE} =5V, I _C =1mA	10			
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =1.2A		15		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		80		pF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C =6A, I _B =1.2A			0.8	V
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =6A, I _B =1.2A			1.5	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=1mA, IE=0	500			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=5mA, RBE=∞	400			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=1mA, IC=0	7			V
Turn-ON Time	ton	IC=7A, IB1=1.4A, IB2=-2.8A, RL=28.6Ω, VCC=200V			0.5	μS
Storage Time	t _{stg}	I _C =7A, I _{B1} =1.4A, I _{B2} =-2.8A, R _L =28.6Ω, V _{CC} =200V			2.5	μS
Fall Time	tf	I _C =7A, I _{B1} =1.4A, I _{B2} =-2.8A, R _L =28.6Ω, V _{CC} =200V			0.3	μS

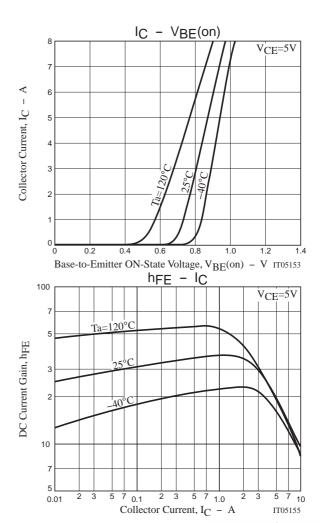
*: The hFE1 of the TT2194 is classified as follows.

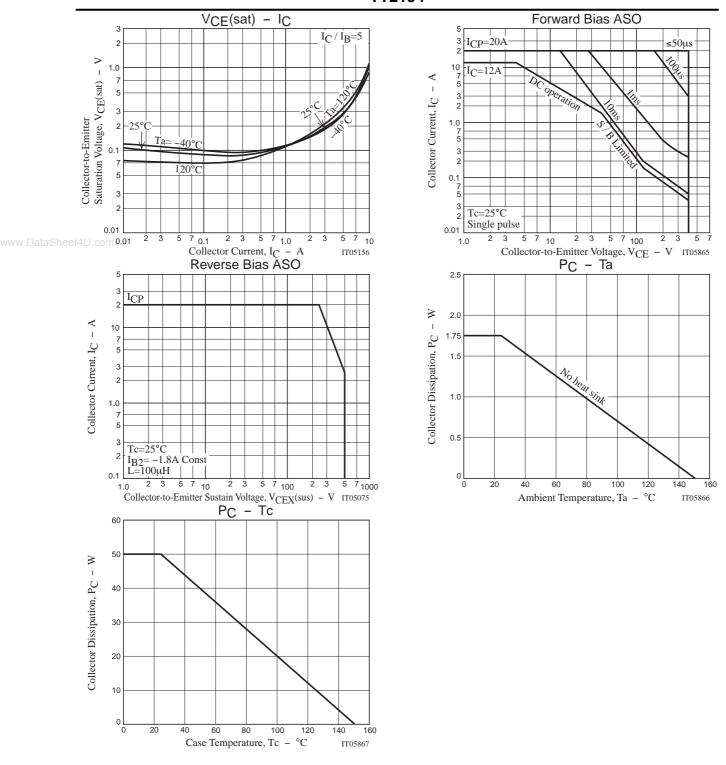
Rank	M	N
hFE	20 to 40	30 to 50

Switching Time Test Circuit









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